INFORMATION DISCLOSURE CITATION

		- APE			
Atty. Docket No.	4329.2309-02	1	ppin. No.	10/655,022	
Applicant	Mizushima et al.	nrt 0 2 2003 ju			
Filing Date	September 5, 2003		rior roup:	2812	
MADEM					

U.S. PATENT DOCUMENTS						
Examiner Initial*	Document Number	Issue Date	Name	Class	Sub Class	Filing Date If Appropriate
RP	2003/0001218A1	1/2/03	Takagi			
RP	6,326,658	12/4/01	Tsunashima et al.			
RP	6,319,782	11/2001	Nakabayashi			
RP	6,124,627	9/2000	Rodder et al.			
RP	5,967,794	10/1999	Kodama			
RP	5,525,828	6/1996	Bassous et al.			
kρ	5,124,276	6/1992	Samata et al.			
RP	4,968,384	11/1990	Asano			

FOREIGN PATENT DOCUMENTS							
	Γ	Document Number	Publication Date	Country	Class	Sub Class	Translation Yes or N
Kβ	T	4-372125	12/25/92	Japan			
RO	T	4-106980	4/8/92	Japan			
	T						

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)					
		Mieno et al., "Selective Doped Polysilicon Growth," Journal of the Electrochemical Society (November 1987), 134:2862-67			
-					

Examiner	Con Pompey	Date Considered /2-/3-0		
*Examiner:	Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.			
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